# MSD1819A-RT1G, SMSD1819A-RT1G

# **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 2.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	-	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10 \mu Adc, I_E = 0$ )	V <sub>(BR)CBO</sub>	60	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_E = 0$ )	V <sub>(BR)EBO</sub>	7.0	-	Vdc
Collector-Base Cutoff Current (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	0.1	μΑ
Collector-Emitter Cutoff Current (V <sub>CE</sub> = 10 Vdc, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	0.1	μΑ
DC Current Gain (Note 2) (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 2.0 mAdc) (V <sub>CE</sub> = 2.0 Vdc, I <sub>C</sub> = 100 mAdc)	h <sub>FE1</sub> h <sub>FE2</sub>	210 90	340 -	_
Collector-Emitter Saturation Voltage (Note 2) (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)		-	0.5	Vdc

<sup>2.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, D.C.  $\leq$  2%.

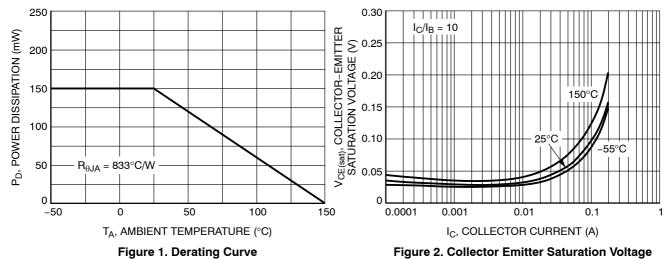


Figure 1. Derating Curve

150°C (2 V)

25°C (10 V)

25°C (2 V)

-55°C (10 V)

-55°C (2 V)

150°C (10 V)

0.1

0.95  $I_{\rm C}/I_{\rm B}=10$ V<sub>BE(sat)</sub>, BASE-EMITTER SATURA-0.85 25°C TION VOLTAGE (V) 0.75 0.65 150°C 0.55 0.45 0.35 0.25 0.0001 0.001 0.01 0.1 IC, COLLECTOR CURRENT (A)

vs. Collector Current

IC, COLLECTOR CURRENT (A) Figure 3. DC Current Gain vs. Collector Current

0.01

Figure 4. Base Emitter Saturation Voltage vs. **Collector Current** 

450

400

350

300

250

200

150

100

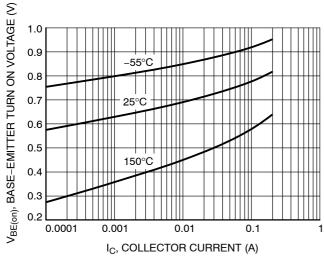
50

0.0001

0.001

h<sub>FE</sub>, DC CURRENT GAIN

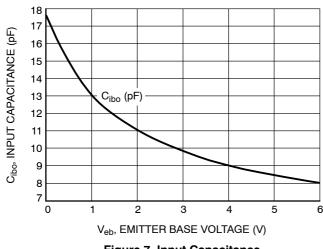
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1.2 1 mA T<sub>A</sub> = 25°C T<sub>A</sub> = 25°C T<sub>A</sub> = 1.0 mA T<sub>A</sub> = 25°C T<sub>A</sub> = 1.0 mA T<sub>A</sub> = 25°C T<sub>A</sub> = 1.0 mA T<sub>A</sub> = 1.0 mA

Figure 5. Base Emitter Turn-On Voltage vs. Collector Current

Figure 6. Collector Saturation Region



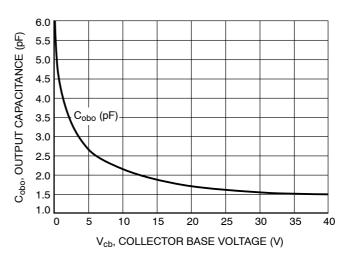


Figure 7. Input Capacitance

Figure 8. Output Capacitance

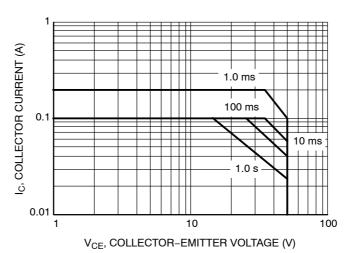
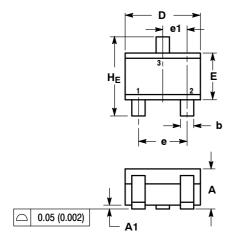


Figure 9. Safe Operating Area

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# PACKAGE DIMENSIONS

# SC-70 (SOT-323) CASE 419-04 ISSUE N



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

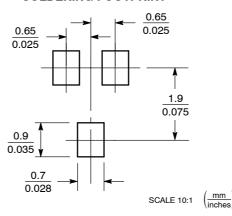
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2		0.70 REF 0.028 REF					
b	0.30	0.35	0.40	0.012	0.014	0.016	
С	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.10	2.20	0.071	0.083	0.087	
E	1.15	1.24	1.35	0.045	0.049	0.053	
е	1.20	1.30	1.40	0.047	0.051	0.055	
e1	0.65 BSC			0.026 BSC			
L	0.20	0.38	0.56	0.008	0.015	0.022	
HE	2.00	2.10	2.40	0.079	0.083	0.095	

A2 C

STYLE 3: PIN 1. BASE

2. EMITTER 3. COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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